

MMBT918LT1

VHF/UHF Transistor

NPN Silicon

Features

- Pb-Free Package is Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	15	Vdc
Collector-Base Voltage	V_{CBO}	30	Vdc
Emitter-Base Voltage	V_{EBO}	3.0	Vdc
Collector Current - Continuous	I_C	50	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C/W}$
Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	$^\circ\text{C/W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

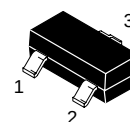
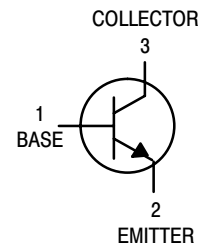
1. FR-5 = 1.0 x 0.75 x 0.062 in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.



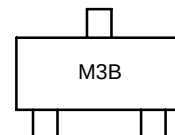
ON Semiconductor®

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SOT-23 (TO-236AF)
CASE 318
Style 6

MARKING DIAGRAM



M3B = Specific Device Code

ORDERING INFORMATION

Device	Package	Shipping†
MMBT918LT1	SOT-23	3000 / Tape & Reel
MMBT918LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

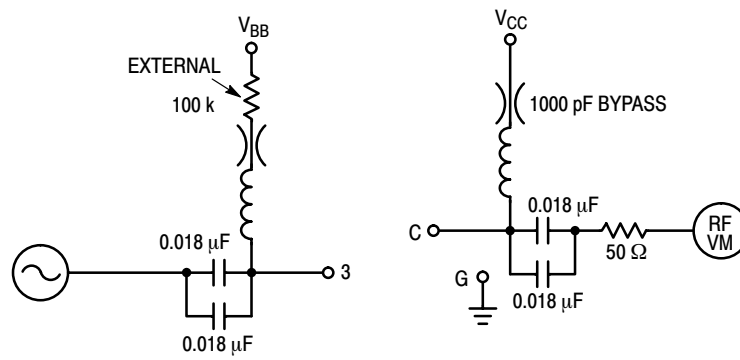
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage ($I_C = 3.0\text{ mA}$, $I_E = 0$)	$V_{(BR)CEO}$	15	–	Vdc
Collector – Base Breakdown Voltage ($I_C = 1.0\text{ }\mu\text{A}$, $I_E = 0$)	$V_{(BR)CBO}$	30	–	Vdc
Emitter – Base Breakdown Voltage ($I_E = 10\text{ }\mu\text{A}$, $I_C = 0$)	$V_{(BR)EBO}$	3.0	–	Vdc
Collector Cutoff Current ($V_{CB} = 15\text{ Vdc}$, $I_E = 0$)	I_{CBO}	–	50	nAdc
ON CHARACTERISTICS				
DC Current Gain ($I_C = 3.0\text{ mA}$, $V_{CE} = 1.0\text{ Vdc}$)	h_{FE}	20	–	–
Collector – Emitter Saturation Voltage ($I_C = 10\text{ mA}$, $I_B = 1.0\text{ mA}$)	$V_{CE(sat)}$	–	0.4	Vdc
Base – Emitter Saturation Voltage ($I_C = 10\text{ mA}$, $I_B = 1.0\text{ mA}$)	$V_{BE(sat)}$	–	1.0	Vdc
SMALL – SIGNAL CHARACTERISTICS				
Current – Gain – Bandwidth Product ($I_C = 4.0\text{ mA}$, $V_{CE} = 10\text{ Vdc}$, $f = 100\text{ MHz}$)	f_T	600	–	MHz
Output Capacitance ($V_{CB} = 0\text{ Vdc}$, $I_E = 0$, $f = 1.0\text{ MHz}$) ($V_{CB} = 10\text{ Vdc}$, $I_E = 0$, $f = 1.0\text{ MHz}$)	C_{obo}	– –	3.0 1.7	pF
Input Capacitance ($V_{EB} = 0.5\text{ Vdc}$, $I_C = 0$, $f = 1.0\text{ MHz}$)	C_{ibo}	–	2.0	pF
Noise Figure ($I_C = 1.0\text{ mA}$, $V_{CE} = 6.0\text{ Vdc}$, $R_S = 50\text{ }\Omega$, $f = 60\text{ MHz}$) (Figure 1)	NF	–	6.0	dB
Power Output ($I_C = 8.0\text{ mA}$, $V_{CB} = 15\text{ Vdc}$, $f = 500\text{ MHz}$)	P_{out}	30	–	mW
Common – Emitter Amplifier Power Gain ($I_C = 6.0\text{ mA}$, $V_{CB} = 12\text{ Vdc}$, $f = 200\text{ MHz}$)	G_{pe}	11	–	dB

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NF TEST CONDITIONS

$I_C = 1.0 \text{ mA}$
 $V_{CE} = 6.0 \text{ VOLTS}$
 $R_S = 50 \Omega$
 $f = 60 \text{ MHz}$

G_{pe} TEST CONDITIONS

$I_C = 6.0 \text{ mA}$
 $V_{CE} = 12 \text{ VOLTS}$
 $f = 200 \text{ MHz}$

Figure 1. NF, G_{pe} Measurement Circuit 20–200

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PACKAGE DIMENSIONS

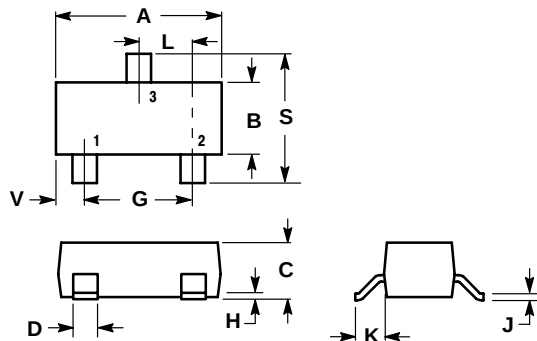
SOT-23 (TO-236)

CASE 318-08

ISSUE AH

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. 318-03 AND -07 OBSOLETE, NEW STANDARD 318-08.

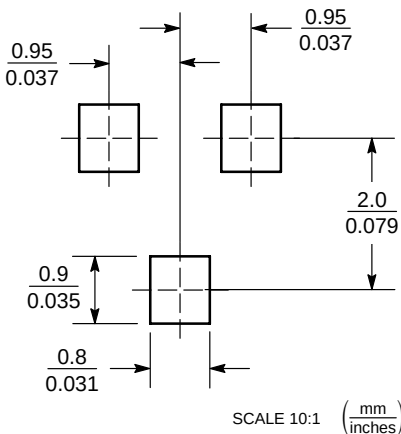


DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

STYLE 6:

- PIN 1. BASE
2. EMITTER
3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

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